
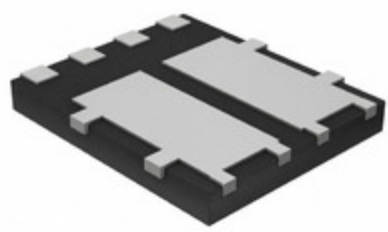
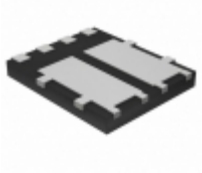
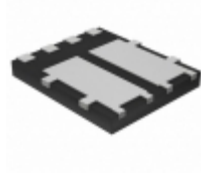
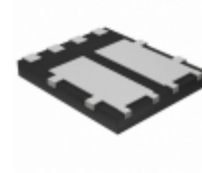
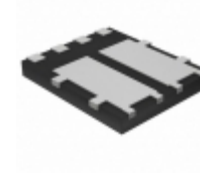
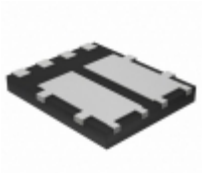
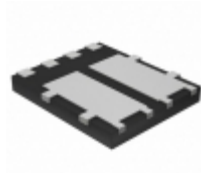
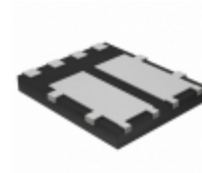
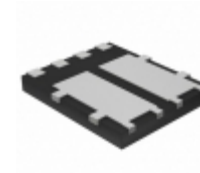
	<p>NVMFD5875NLT1G</p> <p>Hersteller-Teilenummer: NVMFD5875NLT1G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET 2N-CH 60V 7A SO8FL</p> <hr/> <p>Datenblätter:  NVMFD5875NLT1G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVMFD5875NLT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2N-CH 60V 7A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	3V @ 250µA
Supplier Device-Gehäuse	8-DFN (5x6) Dual Flag (SO8FL-Dual-Asymmetrical)
Serie	-
Rds On (Max) @ Id, Vgs	33 mOhm @ 7.5A, 10V
Leistung - max	3.2W
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	8-PowerTDFN
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	540pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	7A

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Sie können auch interessiert

<p>sein:</p>  <p>NVMFD5853NLWFT1G ON Semiconductor MOSFET 2N-CH 40V 12A SO8FL</p>	 <p>NVMFD5877NLT1G ON Semiconductor MOSFET 2N-CH 60V 6A 8SOIC</p>	 <p>NVMFD5873NLWFT1G ON Semiconductor MOSFET 2N-CH 60V 10A SO8FL</p>	 <p>NVMFD5853NT1G ON Semiconductor MOSFET 2N-CH 40V 12A SO8FL</p>
 <p>NVMFD5875NLT3G ON Semiconductor MOSFET 2N-CH 60V 7A SO8FL</p>	 <p>NVMFD5875NLWFT3G ON Semiconductor MOSFET 2N-CH 60V 7A SO8FL</p>	 <p>NVMFD5875NLWFT1G ON Semiconductor MOSFET 2N-CH 60V 7A SO8FL</p>	 <p>NVMFD5877NLT3G ON Semiconductor MOSFET 2N-CH 60V 6A 8SOIC</p>

Verwandtes Hot-Keyword

Mehr

NVMFD5875NLT1G AMI Semiconductor / ON Semiconductor	NVMFD5875NLT1G Datenblatt	NVMFD5875NLT1G-Datenblätter	NVMFD5875NLT1G PDF	AMI Semiconductor / ON Semiconductor NVMFD5875NLT1G
NVMFD5875NLT1G Electronic	NVMFD5875NLT1G-Komponenten	NVMFD5875NLT1G-Verteiler	NVMFD5875NLT1G-Bild	NVMFD5875NLT1G-Teil
NVMFD5875NLT1G Preis	NVMFD5875NLT1G Hersteller	NVMFD5875NLT1G Bild	NVMFD5875NLT1G Aktie	NVMFD5875NLT1G Inventar
NVMFD5875NLT1G Neu	NVMFD5875NLT1G Original	NVMFD5875NLT1G garantiert	NVMFD5875NLT1G RFQ	NVMFD5875NLT1G Online bestellen

Contact us: Info@Y-IC.com

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